## NSN 5961-01-150-4605

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View Online at https://aerobasegroup.com/nsn/5961-01-150-4605

**Inclosure Material:** 

Metal

**Overall Length:** 

1.573 inches

**Terminal Length:** 

Between 0.312 inches and 0.500 inches

**Overall Height:** 

Between 0.270 inches and 0.380 inches

**Overall Width:** 

1.050 inches

**Mounting Facility Quantity:** 

2

**Internal Configuration:** 

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

**Electrode Internally-electrically Connected To Case:** 

Collector

**Mounting Method:** 

Terminal and unthreaded hole

**Features Provided:** 

Hermetically sealed case and quality assurance level txv

**Semiconductor Material:** 

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 collector to base voltage/static/emitter open and 7.0 emitter to base voltage, static, collector open and 60.0 collector to emitter voltage/static/base open

**Current Rating Per Characteristic:** 

10.00 amperes source cutoff current

**Power Rating Per Characteristic:** 

5.0 watts small-signal input power, common-collector preset

**Maximum Operating Tempurature Per Measurement Point:** 

200.0 degrees celsius ambient air

**Special Features:** 

Junction pattern arrangement: npn

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

**Terminal Type And Quantity:** 

1 case and 2 uninsulated wire lead

**Specification Data:** 

81349-mil-s-19500/379 government specification

Shelf Life:

NI/o

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Demilitarization:

No

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